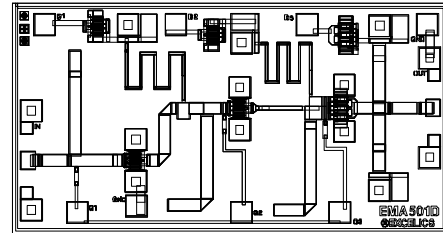


TENTATIVE DATA SHEET
36 - 40 GHz Medium Power MMIC
FEATURES

- 36 -40 GHz BANDWIDTH
- +21 dBm OUTPUT POWER @1dB Gain Compression
- 23 dB TYPICAL POWER GAIN
- DUAL BIAS SUPPLY
- 0.3 MICRON RECESSED “MUSHROOM” GATE
- Si₃N₄ PASSIVATION
- ADVANCED EPITAXIAL HETEROJUNCTION PROFILE PROVIDES EXTRA HIGH POWER EFFICIENCY, AND HIGH RELIABILITY



Chip Size 1060 x 2000 microns
Chip Thickness: 75 ± 13 microns
All Dimensions In Microns

ELECTRICAL CHARACTERISTICS¹ (T_a = 25 °C)

SYMBOL	PARAMETERS/TEST CONDITIONS	MIN	TYP	MAX	UNIT
F	Operating Frequency Range	36		40	GHz
P_{1dB}	Output Power at 1dB Gain Compression @ V _{dd} =8V		21		dBm
G_{ss}	Small Signal Gain		23		dB
ΔG_{ss}	Small Signal Gain Flatness		± 3		dB
NF	Noise Figure @ V _{dd} =3.5V, I _d =100mA		6		dB
VSWR_{in}	Input VSWR		3.0:1		
VSWR_{out}	Output VSWR		3.0:1		
I_{dd}	Power Supply Current		100		mA
V_{dd}	Power Supply Voltage		6	8	V

MAXIMUM RATINGS AT 25°C

SYMBOLS	PARAMETERS	ABSOLUTE ¹	CONTINUOUS ²
V_{ds}	Drain-Source Voltage	12V	8V
V_{gs}	Gate-Source Voltage	-8V	-3V
I_{ds}	Drain Current	I _{dss}	150mA
I_{gf}	Forward Gate Current	36 mA	6mA
P_{in}	Input Power	15dBm	@3dB Compression
T_{ch}	Channel Temperature	175°C	150°C
T_{stg}	Storage Temperature	-65/175°C	-65/150°C
P_t	Total Power Dissipation	0.7 W	0.6 W

Note: 1. Exceeding any of the above ratings may result in permanent damage.
2. Exceeding any of the above ratings may reduce MTTF below design goals.

TENTATIVE DATA SHEET

36 - 40 GHz Medium Power MMIC

S-PARAMETERS (On wafer Sij measurements)

6V, 1/2 Idss

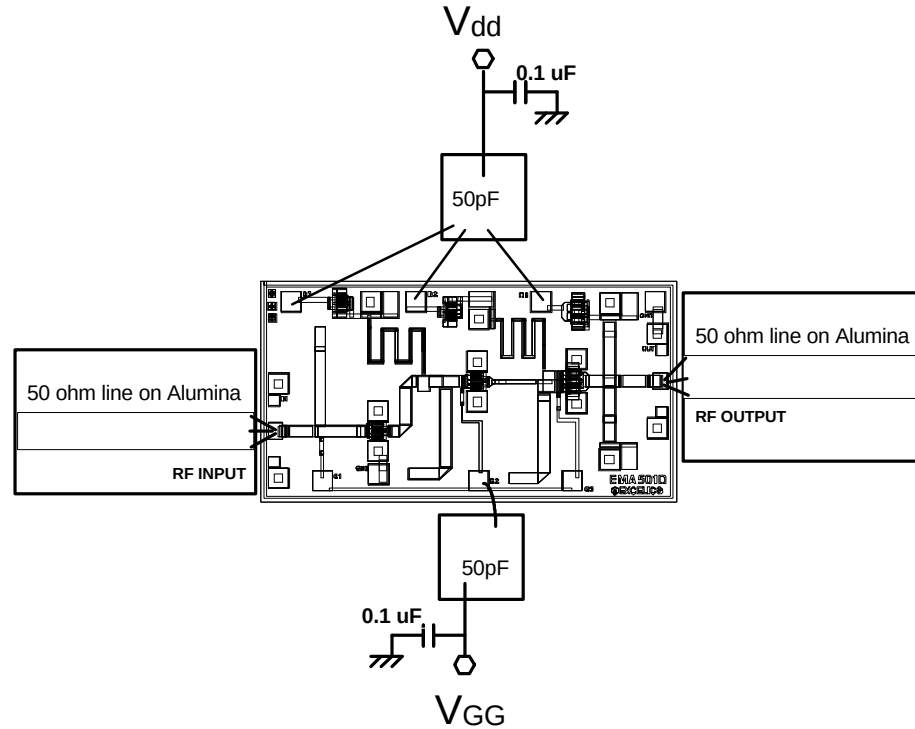
FREQ	--- S11 ---		--- S21 ---		--- S12 ---		--- S22 ---	
(GHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
20	0.88	95.78	0.54	-131.62	0.00774	-73.25	0.77	169.14
20.5	0.88	56.78	0.51	179.1	0.01004	-119.89	0.74	116.47
21	0.88	16.47	0.5	129.26	0.0196	-157.56	0.7	64.36
21.5	0.87	-22.14	0.54	81.91	0.00955	138.43	0.68	10.98
22	0.87	-60.86	0.58	29.04	0.0091	19.45	0.66	-43.72
22.5	0.89	-100.53	0.6	-28.44	0.01221	45.26	0.68	-104.2
23	0.9	-141.74	0.55	-79.42	0.01159	-27.16	0.64	-157.52
23.5	0.9	178.2	0.53	-127.32	0.01764	-97.15	0.66	150.18
24	0.89	137.16	0.56	-178.49	0.01938	-157.25	0.7	97.11
24.5	0.88	97.89	0.56	131.81	0.0171	127.52	0.7	44.62
25	0.89	58.37	0.59	82.52	0.00817	169.71	0.82	-7.94
25.5	0.9	18.71	0.61	31.95	0.01686	24.15	0.84	-65.12
26	0.89	-20.57	0.62	-17.95	0.01075	7.41	0.83	-120.08
26.5	0.9	-60.59	0.66	-68.68	0.0053	-61.16	0.85	-175.03
27	0.89	-99.22	0.68	-120.71	0.00661	-115.41	0.84	131.47
27.5	0.9	-138.01	0.71	-168.08	0.01248	128.84	0.82	80.43
28	0.9	-175.23	0.75	140.45	0.01793	146.77	0.82	29.89
28.5	0.91	147.69	0.79	90.11	0.0209	67.84	0.82	-22.13
29	0.92	110.9	0.85	39.36	0.01016	11.78	0.8	-75.59
29.5	0.91	74.51	0.92	-10.36	0.01996	-30.36	0.83	-128.62
30	0.92	38.82	1.04	-62.03	0.01277	-106.17	0.83	178.04
30.5	0.91	2.44	1.18	-111.89	0.00432	-134.92	0.83	125
31	0.93	-33.92	1.38	-162.21	0.01081	-162.42	0.82	75.11
31.5	0.93	-74.1	1.64	143.59	0.02166	102.48	0.79	24.92
32	0.92	-113.7	1.95	90.07	0.01219	41.32	0.74	-28.29
32.5	0.92	-152.54	2.37	36.06	0.03323	3.33	0.7	-85.82
33	0.87	163.71	2.85	-21.9	0.02723	-59.98	0.69	-143.25
33.5	0.86	124	3.5	-79.66	0.02304	-109.88	0.7	160.32
34	0.82	84.44	4.39	-135.98	0.01801	176	0.7	107.12
34.5	0.76	44.2	5.67	162.42	0.02775	126.35	0.68	54.65
35	0.72	8.33	7.38	96.75	0.03777	38.52	0.64	8.22
35.5	0.5	-29.82	9.61	28.53	0.01464	37.61	0.61	-41.38
36	0.47	-57.01	11.63	-46.76	0.01766	-29.11	0.58	-96.55
36.5	0.42	-82.11	12.09	-126.76	0.02014	-71.2	0.52	-160.03
37	0.5	-120.85	10.95	162.06	0.02283	-131.79	0.43	139.76
37.5	0.43	-164.88	11.18	95.73	0.00925	-160.55	0.35	69.42
38	0.35	149.59	11.59	25.16	0.00764	117.19	0.2	1.53
38.5	0.23	103.09	11.75	-48.41	0.01062	156.47	0.04	36.25
39	0.12	24.58	11.32	-119.9	0.01383	128.72	0.23	39.95
39.5	0.15	-135.91	11.23	163.55	0.01914	104.31	0.45	-15.91
40	0.42	128.14	10.4	83.06	0.02972	25.72	0.62	-85.03

EMA501D

TENTATIVE DATA SHEET

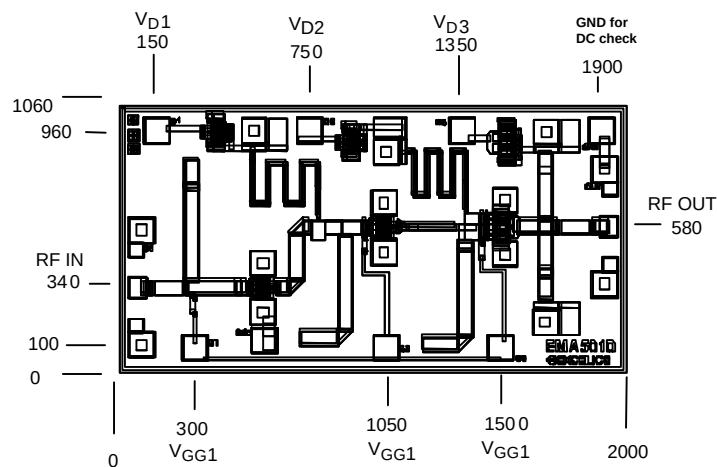
36 - 40 GHz Medium Power MMIC

ASSEMBLY DRAWING



The length of RF wires should be as short as possible. Use at least three wires between RF pad and 50 ohm line and separate the wires to minimize the mutual inductance.

CHIP OUTLINE



Chip Size 1060 x 2000 microns
Chip Thickness: 75 ± 13 microns
PAD Dimensions: 1. DC 100 x 100 microns
2. RF 80 x 68 microns
All Dimensions In Microns

TENTATIVE DATA SHEET

36 - 40 GHz Medium Power MMIC

TYPICAL APPLICATION PERFORMANCE

